

# 14-Stage Binary Ripple Counter With Oscillator

High-Performance Silicon-Gate CMOS

## MC74HC4060A

The MC74HC4060A is identical in pinout to the standard CMOS MC14060B. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

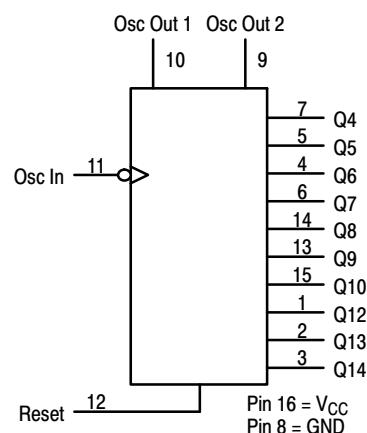
This device consists of 14 master-slave flip-flops and an oscillator with a frequency that is controlled either by a crystal or by an RC circuit connected externally. The output of each flip-flop feeds the next and the frequency at each output is half of that of the preceding one. The state of the counter advances on the negative-going edge of the Osc In. The active-high Reset is asynchronous and disables the oscillator to allow very low power consumption during stand-by operation.

State changes of the Q outputs do not occur simultaneously because of internal ripple delays. Therefore, decoded output signals are subject to decoding spikes and may have to be gated with Osc Out 2 of the HC4060A.

### Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1  $\mu$ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With JEDEC Standard No. 7A Requirements
- Chip Complexity: 390 FETs or 97.5 Equivalent Gates
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### LOGIC DIAGRAM

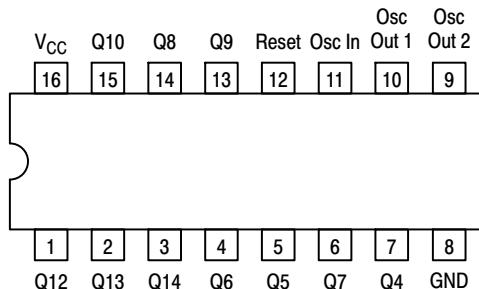


SOIC-16  
D SUFFIX  
CASE 751B



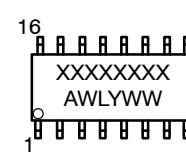
TSSOP-16  
DT SUFFIX  
CASE 948F

### PIN ASSIGNMENT

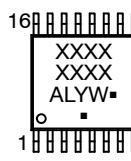


16-Lead Package (Top View)

### MARKING DIAGRAMS



SOIC-16



TSSOP-16

A = Assembly Location  
 L, WL = Wafer Lot  
 Y, YY = Year  
 W, WW = Work Week  
 G or □ = Pb-Free Package

(Note: Microdot may be in either location)

### FUNCTION TABLE

| Clock | Reset | Output State          |
|-------|-------|-----------------------|
| —     | L     | No Change             |
| —     | L     | Advance to Next State |
| X     | H     | All Outputs Are Low   |

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NOTE: Some of the device on this data sheet have been DISCONTINUED. Please refer to the table on page 5

# MC74HC4060A

## MAXIMUM RATINGS

| Symbol        | Parameter  | Value                                    | Unit                 |
|---------------|--|--|----------------------|
| $V_{CC}$      | DC Supply Voltage  | -0.5 to +6.5                             | V                    |
| $V_{IN}$      | DC Input Voltage   | -0.5 to $V_{CC}+0.5$                     | V                    |
| $V_{OUT}$     | DC Output Voltage  | -0.5 to $V_{CC}+0.5$                     | V                    |
| $I_{IN}$      | DC Input Diode Current, per Pin                              | $\pm 20$                                 | mA                   |
| $I_{OUT}$     | DC Input Diode Current, Per Pin                              | $\pm 25$                                 | mA                   |
| $I_{CC}$      | DC Supply Current, $V_{CC}$ and GND Pins                     | $\pm 50$                                 | mA                   |
| $I_{IK}$      | Input Clamp Current ( $V_{IN} < 0$ or $V_{IN} > V_{CC}$ )    | $\pm 20$                                 | mA                   |
| $I_{OK}$      | Output Clamp Current ( $V_{OUT} < 0$ or $V_{OUT} > V_{CC}$ ) | $\pm 20$                                 | mA                   |
| $T_{STG}$     | Storage Temperature Range                                    | -65 to +150                              | °C                   |
| $T_L$         | Lead Temperature, 1 mm from Case for 10 secs                 | 260                                      | °C                   |
| $T_J$         | Junction Temperature Under Bias                              | +150                                     | °C                   |
| $\theta_{JA}$ | Thermal Resistance (Note 1)                                  | SOIC-16<br>TSSOP-16                      | 126<br>159<br>°C/W   |
| $P_D$         | Power Dissipation in Still Air at 25 °C                      | SOIC-16<br>TSSOP-16                      | 995<br>787<br>mW     |
| MSL           | Moisture Sensitivity   | Level 1                                  | -                    |
| $F_R$         | Flammability Rating  | Oxygen Index: 28 to 34                   | UL 94 V-0 @ 0.125 in |
| $V_{ESD}$     | ESD Withstand Voltage (Note 2)                               | Human Body Model<br>Charged Device Model | > 2000<br>N/A<br>V   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
2. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

## RECOMMENDED OPERATING CONDITIONS

| Symbol            | Parameter                         | Min  | Max              | Unit                            |
|-------------------|-----------------------------------|--|------------------|---------------------------------|
| $V_{CC}$          | DC Supply Voltage                 | 2.5*   | 6.0              | V                               |
| $V_{IN}, V_{OUT}$ | DC Input, Output Voltage (Note 3) | 0  | $V_{CC}$         | V                               |
| $T_A$             | Operating Free-Air Temperature    | -55  | +125             | °C                              |
| $t_r, t_f$        | Input Rise or Fall Time           | $V_{CC} = 2.0$ V<br>$V_{CC} = 3.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 6.0$ V | 0<br>0<br>0<br>0 | 1000<br>600<br>500<br>400<br>ns |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

\* The oscillator is guaranteed to function at 2.5 V minimum. However, parametrics are tested at 2.0 V by driving Pin 11 with an external clock source.

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## DC CHARACTERISTICS

| Symbol          | Parameter   | Condition  | V <sub>CC</sub><br>V     | Guaranteed Limit             |                              |                              | Unit |
|-----------------|---|--|--------------------------|------------------------------|------------------------------|------------------------------|------|
|                 |   |  |                          | -55 to 25 °C                 | ≤85 °C                       | ≤125 °C                      |      |
| V <sub>IH</sub> | Minimum High-Level Input Voltage                            | V <sub>out</sub> = 0.1V or V <sub>CC</sub> – 0.1V<br> I <sub>out</sub>   ≤ 20µA  | 2.0<br>3.0<br>4.5<br>6.0 | 1.50<br>2.10<br>3.15<br>4.20 | 1.50<br>2.10<br>3.15<br>4.20 | 1.50<br>2.10<br>3.15<br>4.20 | V    |
| V <sub>IL</sub> | Maximum Low-Level Input Voltage                             | V <sub>out</sub> = 0.1V or V <sub>CC</sub> – 0.1V<br> I <sub>out</sub>   ≤ 20µA  | 2.0<br>3.0<br>4.5<br>6.0 | 0.50<br>0.90<br>1.35<br>1.80 | 0.50<br>0.90<br>1.35<br>1.80 | 0.50<br>0.90<br>1.35<br>1.80 | V    |
| V <sub>OH</sub> | Minimum High-Level Output Voltage<br>(Q4–Q10, Q12–Q14)      | V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub><br> I <sub>out</sub>   ≤ 20µA   | 2.0<br>4.5<br>6.0        | 1.9<br>4.4<br>5.9            | 1.9<br>4.4<br>5.9            | 1.9<br>4.4<br>5.9            | V    |
|                 |   | V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub><br> I <sub>out</sub>   ≤ 2.4 mA<br> I <sub>out</sub>   ≤ 4.0 mA<br> I <sub>out</sub>   ≤ 5.2 mA | 3.0<br>4.5<br>6.0        | 2.48<br>3.98<br>5.48         | 2.34<br>3.84<br>5.34         | 2.20<br>3.70<br>5.20         |      |
| V <sub>OL</sub> | Maximum Low-Level Output Voltage<br>(Q4–Q10, Q12–Q14)       | V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub><br> I <sub>out</sub>   ≤ 20µA   | 2.0<br>4.5<br>6.0        | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | V    |
|                 |   | V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub><br> I <sub>out</sub>   ≤ 2.4 mA<br> I <sub>out</sub>   ≤ 4.0 mA<br> I <sub>out</sub>   ≤ 5.2 mA | 3.0<br>4.5<br>6.0        | 0.26<br>0.26<br>0.26         | 0.33<br>0.33<br>0.33         | 0.40<br>0.40<br>0.40         |      |
| V <sub>OH</sub> | Minimum High-Level Output Voltage<br>(Osc Out 1, Osc Out 2) | V <sub>in</sub> = V <sub>CC</sub> or GND<br> I <sub>out</sub>   ≤ 20µA   | 2.0<br>4.5<br>6.0        | 1.9<br>4.4<br>5.9            | 1.9<br>4.4<br>5.9            | 1.9<br>4.4<br>5.9            | V    |
|                 |   | V <sub>in</sub> = V <sub>CC</sub> or GND<br> I <sub>out</sub>   ≤ 0.7 mA<br> I <sub>out</sub>   ≤ 1.0 mA<br> I <sub>out</sub>   ≤ 1.3 mA             | 3.0<br>4.5<br>6.0        | 2.48<br>3.98<br>5.48         | 2.34<br>3.84<br>5.34         | 2.20<br>3.70<br>5.20         |      |
| V <sub>OL</sub> | Maximum Low-Level Output Voltage<br>(Osc Out 1, Osc Out 2)  | V <sub>in</sub> = V <sub>CC</sub> or GND<br> I <sub>out</sub>   ≤ 20µA   | 2.0<br>4.5<br>6.0        | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | 0.1<br>0.1<br>0.1            | V    |
|                 |   | V <sub>in</sub> = V <sub>CC</sub> or GND<br> I <sub>out</sub>   ≤ 0.7 mA<br> I <sub>out</sub>   ≤ 1.0 mA<br> I <sub>out</sub>   ≤ 1.3 mA             | 3.0<br>4.5<br>6.0        | 0.26<br>0.26<br>0.26         | 0.33<br>0.33<br>0.33         | 0.40<br>0.40<br>0.40         |      |
| I <sub>in</sub> | Maximum Input Leakage Current                               | V <sub>in</sub> = V <sub>CC</sub> or GND   | 6.0                      | ±0.1                         | ±1.0                         | ±1.0                         | µA   |
| I <sub>CC</sub> | Maximum Quiescent Supply Current (per Package)              | V <sub>in</sub> = V <sub>CC</sub> or GND<br>I <sub>out</sub> = 0µA   | 6.0                      | 4                            | 40                           | 160                          | µA   |

## AC CHARACTERISTICS (C<sub>L</sub> = 50 pF)

| Symbol                                 | Parameter  | V <sub>CC</sub><br>V     | Guaranteed Limit         |                          |                           | Unit |
|--|--|--------------------------|--------------------------|--------------------------|---------------------------|------|
|  |  |                          | -55 to 25 °C             | ≤85 °C                   | ≤125 °C                   |      |
| f <sub>max</sub>                       | Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 1 and 4)  | 2.0<br>3.0<br>4.5<br>6.0 | 6.0<br>10<br>30<br>50    | 9.0<br>14<br>28<br>45    | 8.0<br>12<br>25<br>40     | MHz  |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Maximum Propagation Delay, Osc In to Q4*<br>(Figures 1 and 4)  | 2.0<br>3.0<br>4.5<br>6.0 | 300<br>180<br>60<br>51   | 375<br>200<br>75<br>64   | 450<br>250<br>90<br>75    | ns   |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Maximum Propagation Delay, Osc In to Q14*<br>(Figures 1 and 4) | 2.0<br>3.0<br>4.5<br>6.0 | 500<br>350<br>250<br>200 | 750<br>450<br>275<br>220 | 1000<br>600<br>300<br>250 | ns   |
| t <sub>PHL</sub>                       | Maximum Propagation Delay, Reset to Any Q<br>(Figures 2 and 4) | 2.0<br>3.0<br>4.5<br>6.0 | 195<br>75<br>39<br>33    | 245<br>100<br>49<br>42   | 300<br>125<br>61<br>53    | ns   |

# MC74HC4060A

## AC CHARACTERISTICS (C<sub>L</sub> = 50 pF) (continued)

| Symbol                                 | Parameter  | V <sub>CC</sub><br>V     | Guaranteed Limit     |                      |                       | Unit |
|--|--|--------------------------|----------------------|----------------------|-----------------------|------|
|  |  |                          | -55 to 25 °C         | ≤85 °C               | ≤125 °C               |      |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Maximum Propagation Delay, Q <sub>n</sub> to Q <sub>n+1</sub><br>(Figures 3 and 4) | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>60<br>15<br>13 | 95<br>75<br>19<br>16 | 125<br>95<br>24<br>20 | ns   |
| t <sub>TLH</sub> ,<br>t <sub>THL</sub> | Maximum Output Transition Time, Any Output<br>(Figures 1 and 4)                    | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>27<br>15<br>13 | 95<br>32<br>19<br>16 | 110<br>36<br>22<br>19 | ns   |
| C <sub>in</sub>                        | Maximum Input Capacitance  |                          | 10                   | 10                   | 10                    | pF   |

\* For T<sub>A</sub> = 25 °C and C<sub>L</sub> = 50 pF, typical propagation delay from Clock to other Q outputs may be calculated with the following equations:

$$V_{CC} = 2.0 \text{ V: } t_p = [93.7 + 59.3 (n-1)] \text{ ns}$$

$$V_{CC} = 4.5 \text{ V: } t_p = [30.25 + 14.6 (n-1)] \text{ ns}$$

$$V_{CC} = 3.0 \text{ V: } t_p = [61.5 + 34.4 (n-1)] \text{ ns}$$

$$V_{CC} = 6.0 \text{ V: } t_p = [24.4 + 12 (n-1)] \text{ ns}$$

| C <sub>PD</sub> | Power Dissipation Capacitance (Per Package)* | Typical @ 25 °C, V <sub>CC</sub> = 5.0 V |  |  | pF |
|-----------------|--|--|--|--|----|
|                 |  | 35                                       |  |  |    |

\* Used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>.

## TIMING REQUIREMENTS

| Symbol                          | Parameter  | V <sub>CC</sub><br>V     | Guaranteed Limit          |                           |                           | Unit |
|---------------------------------|--|--------------------------|---------------------------|---------------------------|---------------------------|------|
|                                 |  |                          | -55 to 25 °C              | ≤85 °C                    | ≤125 °C                   |      |
| t <sub>rec</sub>                | Minimum Recovery Time, Reset Inactive to Clock<br>(Figure 2) | 2.0<br>3.0<br>4.5<br>6.0 | 100<br>75<br>20<br>17     | 125<br>100<br>25<br>21    | 150<br>120<br>30<br>25    | ns   |
| t <sub>w</sub>                  | Minimum Pulse Width, Clock<br>(Figure 1)                     | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>27<br>15<br>13      | 95<br>32<br>19<br>16      | 110<br>36<br>23<br>19     | ns   |
| t <sub>w</sub>                  | Minimum Pulse Width, Reset<br>(Figure 2)                     | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>27<br>15<br>13      | 95<br>32<br>19<br>16      | 110<br>36<br>23<br>19     | ns   |
| t <sub>r</sub> , t <sub>f</sub> | Maximum Input Rise and Fall Times<br>(Figure 1)              | 2.0<br>3.0<br>4.5<br>6.0 | 1000<br>800<br>500<br>400 | 1000<br>800<br>500<br>400 | 1000<br>800<br>500<br>400 | ns   |

# MC74HC4060A

## ORDERING INFORMATION

| Device           | Marking     | Package               | Shipping <sup>†</sup> |
|------------------|-------------|-----------------------|-----------------------|
| MC74HC4060ADR2G  | HC4060AG    | SOIC-16<br>(Pb-Free)  | 2500 Units / Reel     |
| MC74HC4060ADTR2G | HC40<br>60A | TSSOP-16<br>(Pb-Free) | 2500 Units / Reel     |

## DISCONTINUED (Note 4)

| Device            | Package               | Shipping <sup>†</sup> |
|-------------------|-----------------------|-----------------------|
| MC74HC4060ADG     | SOIC-16<br>(Pb-Free)  | 48 Units / Rail       |
| NLV74HC4060ADR2G* | SOIC-16<br>(Pb-Free)  | 2500 Units / Reel     |
| MC74HC4060ADTG    | TSSOP-16<br>(Pb-Free) | 96 Units / Rail       |
| NLVHC4060ADTR2G*  | TSSOP-16<br>(Pb-Free) | 2500 Units / Reel     |

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

4. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on [www.onsemi.com](#).

\* -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## PIN DESCRIPTIONS

## INPUTS

## Osc In (Pin 11)

Negative-edge triggering clock input. A high-to-low transition on this input advances the state of the counter. Osc In may be driven by an external clock source.

## Reset (Pin 12)

Active-high reset. A high level applied to this input asynchronously resets the counter to its zero state (forcing all Q outputs low) and disables the oscillator.

## OUTPUTS

## Q4–Q10, Q12–Q14 (Pins 7, 5, 4, 6, 13, 15, 1, 2, 3)

Active-high outputs. Each Qn output divides the Clock input frequency by  $2^N$ . The user should note the Q1, Q2, Q3 and Q11 are not available as outputs.

## Osc Out 1, Osc Out 2 (Pins 9, 10)

Oscillator outputs. These pins are used in conjunction with Osc In and the external components to form an oscillator. When Osc In is being driven with an external clock source, Osc Out 1 and Osc Out 2 must be left open circuited. With the crystal oscillator configuration in Figure 6, Osc Out 2 must be left open circuited.

## SWITCHING WAVEFORMS

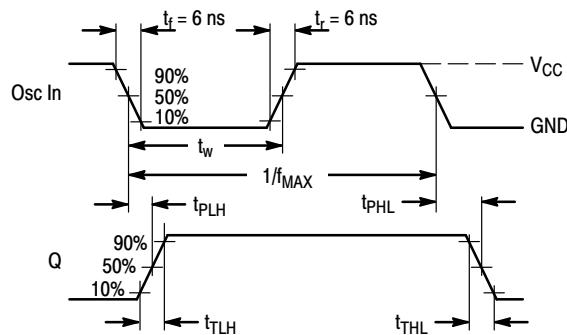


Figure 1.

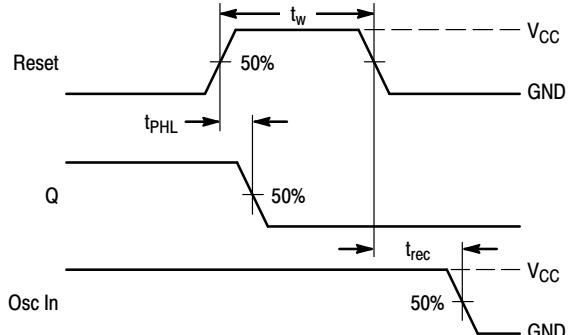


Figure 2.

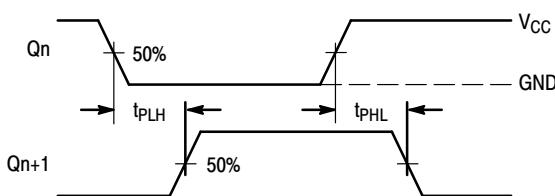
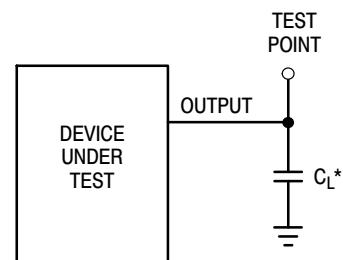


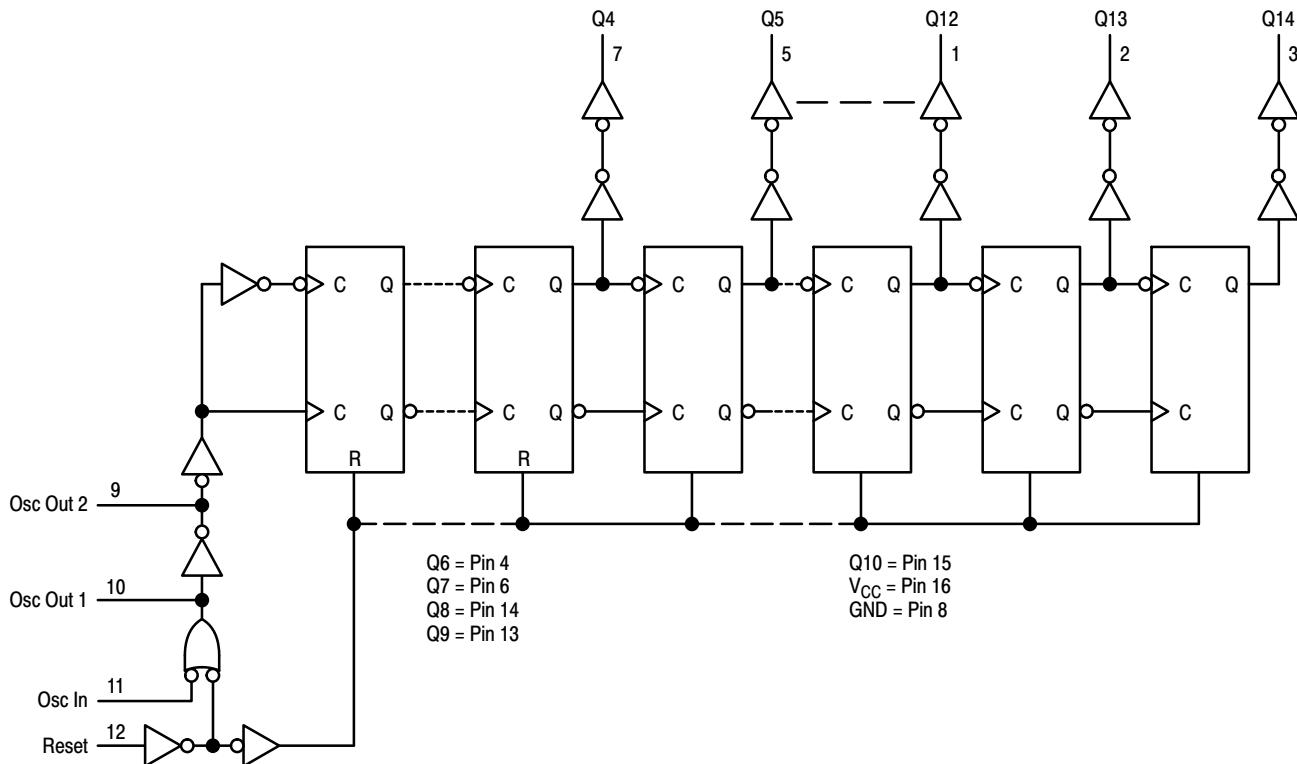
Figure 3.



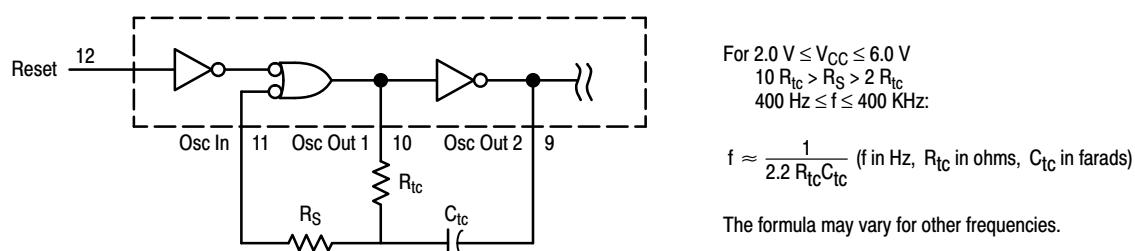
\*Includes all probe and jig capacitance

Figure 4. Test Circuit

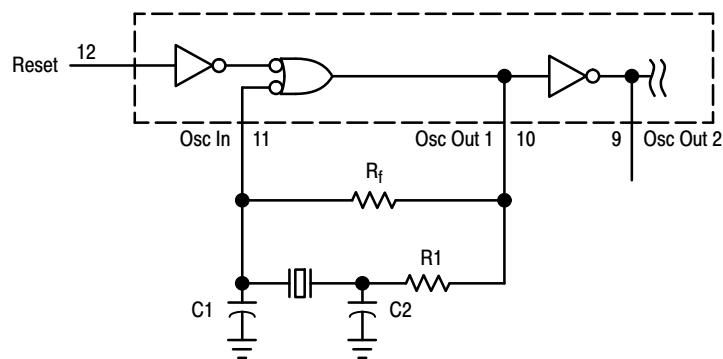
## MC74HC4060A



**Figure 5. Expanded Logic Diagram**



**Figure 6. Oscillator Circuit Using RC Configuration**

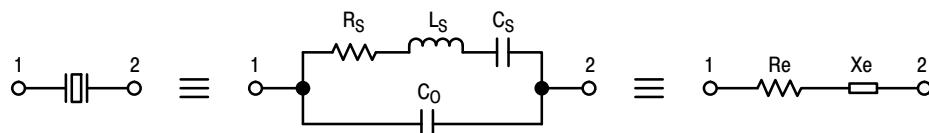


**Figure 7. Pierce Crystal Oscillator Circuit**

TABLE 1. CRYSTAL OSCILLATOR AMPLIFIER SPECIFICATIONS ( $T_A = 25^\circ\text{C}$ ; Input = Pin 11, Output = Pin 10)

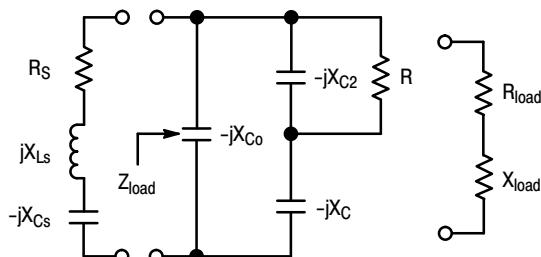
| Type   | Positive Reactance (Pierce)  |
|--|--|
| Input Resistance, $R_{in}$                                 | 60 M $\Omega$ Minimum  |
| Output Impedance, $Z_{out}$ (4.5 V Supply)                 | 200 $\Omega$ (See Text)  |
| Input Capacitance, $C_{in}$                                | 5 pF Typical   |
| Output Capacitance, $C_{out}$                              | 7 pF Typical   |
| Series Capacitance, $C_a$                                  | 5 pF Typical   |
| Open Loop Voltage Gain with Output at Full Swing, $\alpha$ | 3 Vdc Supply      5.0 Expected Minimum<br>4 Vdc Supply      4.0 Expected Minimum<br>5 Vdc Supply      3.3 Expected Minimum<br>6 Vdc Supply      3.1 Expected Minimum |

### PIERCE CRYSTAL OSCILLATOR DESIGN



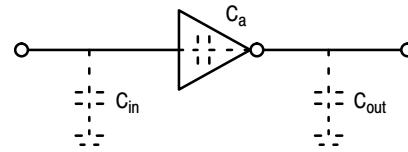
Values are supplied by crystal manufacturer (parallel resonant crystal).

Figure 8. Equivalent Crystal Networks



NOTE:  $C = C_1 + C_{in}$  and  $R = R_1 + R_{out}$ .  $C_0$  is considered as part of the load.  $C_a$  and  $R_f$  typically have minimal effect below 2 MHz.

Figure 9. Series Equivalent Crystal Load



Values are listed in Table 1.

Figure 10. Parasitic Capacitances of the Amplifier

**DESIGN PROCEDURES**

The following procedure applies for oscillators operating below 2 MHz where  $Z$  is a resistor  $R_1$ . Above 2 MHz, additional impedance elements should be considered:  $C_{out}$  and  $C_a$  of the amp, feedback resistor  $R_f$ , and amplifier phase shift error from 180 °C.

Step 1: Calculate the equivalent series circuit of the crystal at the frequency of oscillation.

$$Z_e = \frac{-jX_{C_0}(R_s + jX_{L_s} - jX_{C_s})}{-jX_{C_0} + R_s + jX_{L_s} - jX_{C_s}} = R_e + jX_e$$

Reactance  $jX_e$  should be positive, indicating that the crystal is operating as an inductive reactance at the oscillation frequency. The maximum  $R_s$  for the crystal should be used in the equation.

Step 2: Determine  $\beta$ , the attenuation, of the feedback network. For a closed-loop gain of  $2, A_v\beta = 2, \beta = 2/A_v$  where  $A_v$  is the gain of the HC4060A amplifier.

Step 3: Determine the manufacturer's loading capacitance. For example: A manufacturer may specify an external load capacitance of 32 pF at the required frequency.

Step 4: Determine the required  $Q$  of the system, and calculate  $R_{load}$ . For example, a manufacturer specifies a crystal  $Q$  of 100,000. In-circuit  $Q$  is arbitrarily set at 20% below crystal  $Q$  or 80,000. Then  $R_{load} = (2\pi f_0 L_s/Q) - R_s$  where  $L_s$  and  $R_s$  are crystal parameters.

Step 5: Simultaneously solve, using a computer,

$$\beta = \frac{X_C \cdot X_{C2}}{R \cdot R_e + X_{C2} (X_e - X_C)} \quad (\text{with feedback phase shift} = 180^\circ) \quad (\text{Eq 1})$$

$$X_e = X_{C2} + X_C + \frac{R_e X_{C2}}{R} = X_{Cload} \quad (\text{where the loading capacitor is an external load, not including } C_0) \quad (\text{Eq 2})$$

$$R_{load} = \frac{R X_{C_0} X_{C2} [(X_C + X_{C2})(X_C + X_{C_0}) - X_C(X_C + X_{C_0} + X_{C2})]}{X^2_{C2}(X_C + X_{C_0})^2 + R^2(X_C + X_{C_0} + X_{C2})^2} \quad (\text{Eq 3})$$

Here  $R = R_{out} + R_1$ .  $R_{out}$  is amp output resistance,  $R_1$  is  $Z$ . The  $C$  corresponding to  $X_C$  is given by  $C = C_1 + C_{in}$ .

Alternately, pick a value for  $R_1$  (i.e, let  $R_1 = R_s$ ). Solve Equations 1 and 2 for  $C_1$  and  $C_2$ . Use Equation 3 and the fact that  $Q = 2\pi f_0 L_s / (R_s + R_{load})$  to find in-circuit  $Q$ . If  $Q$  is not satisfactory pick another value for  $R_1$  and repeat the procedure.

**CHOOSING R1**

Power is dissipated in the effective series resistance of the crystal. The drive level specified by the crystal manufacturer is the maximum stress that a crystal can withstand without damage or excessive shift in frequency.  $R_1$  limits the drive level.

To verify that the maximum dc supply voltage does not overdrive the crystal, monitor the output frequency as a function of voltage at Osc Out 2 (Pin 9). The frequency should increase very slightly as the dc supply voltage is increased. An overdriven crystal will decrease in frequency or become unstable with an increase in supply voltage. The operating supply voltage must be reduced or  $R_1$  must be increased in value if the overdriven condition exists. The user should note that the oscillator start-up time is proportional to the value of  $R_1$ .

**SELECTING R<sub>f</sub>**

The feedback resistor,  $R_f$ , typically ranges up to 20 MΩ.  $R_f$  determines the gain and bandwidth of the amplifier. Proper bandwidth insures oscillation at the correct frequency plus roll-off to minimize gain at undesirable frequencies, such as the first overtone.  $R_f$  must be large

enough so as to not affect the phase of the feedback network in an appreciable manner.

**ACKNOWLEDGEMENTS AND RECOMMENDED REFERENCES**

The following publications were used in preparing this data sheet and are hereby acknowledged and recommended for reading:

Technical Note TN-24, Statek Corp.

Technical Note TN-7, Statek Corp.

D. Babin, "Designing Crystal Oscillators", Machine Design, March 7, 1985.

D. Babin, "Guidelines for Crystal Oscillator Design", Machine Design, April 25, 1985.

**ALSO RECOMMENDED FOR READING:**

E. Hafner, "The Piezoelectric Crystal Unit-Definitions and Method of Measurement", Proc. IEEE, Vol. 57, No. 2, Feb., 1969.

D. Kemper, L. Rosine, "Quartz Crystals for Frequency Control", Electro-Technology, June, 1969.

P. J. Ottowitz, "A Guide to Crystal Selection", Electronic Design, May, 1966.

## MC74HC4060A

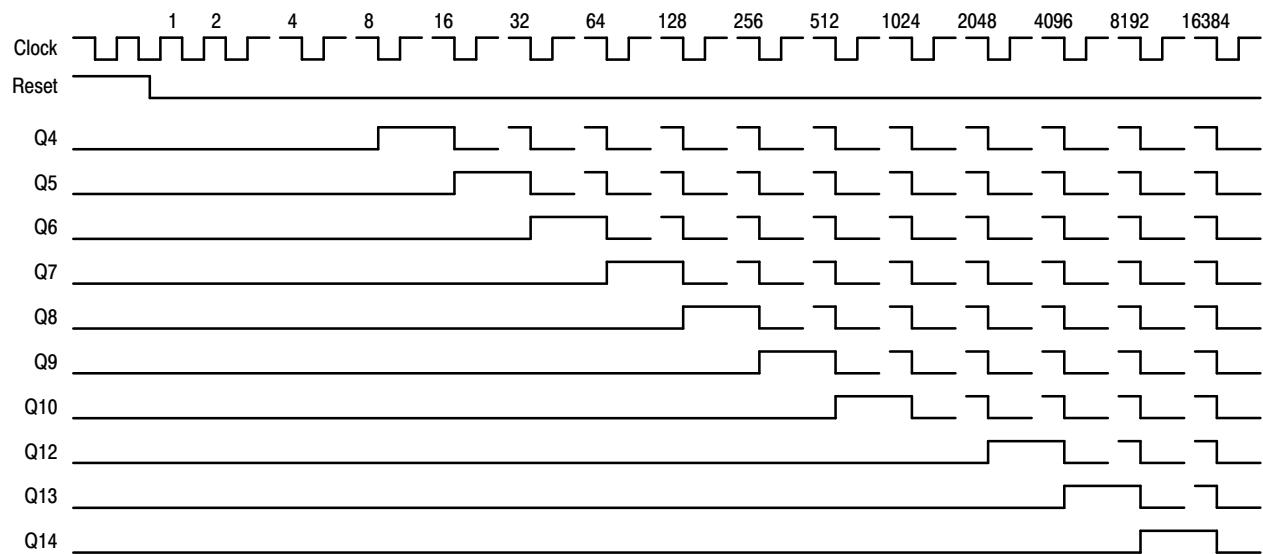


Figure 11. Timing Diagram

# MC74HC4060A

## REVISION HISTORY

| Revision | Description of Changes  | Date       |
|----------|---|------------|
| 12       | Marking Diagrams update (p.1); "NLV Prefix" changed to "-Q Suffix" (p.1, p.5); Updates of Maximum Ratings table, Recommended Operating Conditions table, Ordering Information table and Figure 1. | 10/20/2025 |

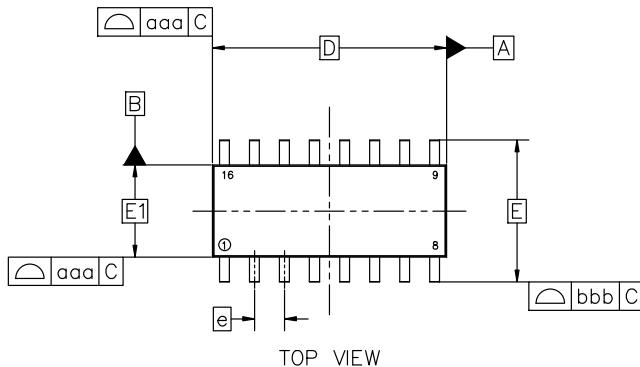
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.


**SOIC-16 9.90x3.90x1.37 1.27P**  
CASE 751B  
ISSUE M

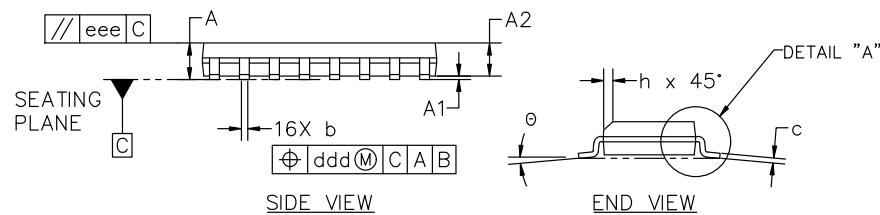
DATE 18 OCT 2024

## NOTES:

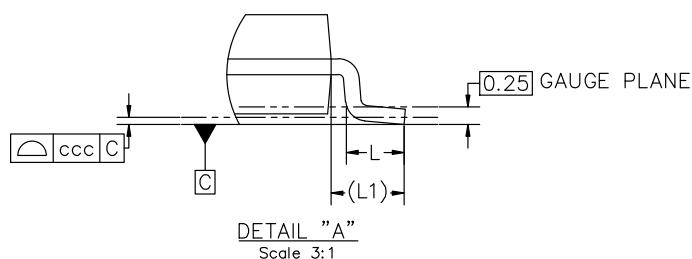
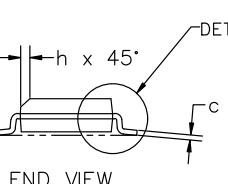
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



TOP VIEW



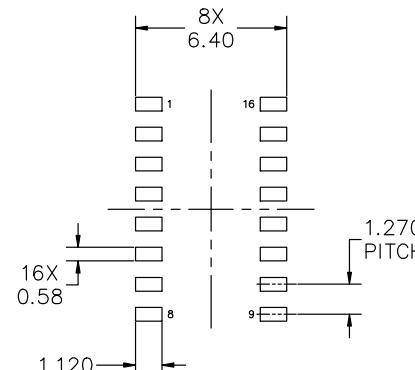
SIDE VIEW



| MILLIMETERS |          |      |      |
|-------------|----------|------|------|
| DIM         | MIN      | NOM  | MAX  |
| A           | 1.35     | 1.55 | 1.75 |
| A1          | 0.10     | 0.18 | 0.25 |
| A2          | 1.25     | 1.37 | 1.50 |
| b           | 0.35     | 0.42 | 0.49 |
| c           | 0.19     | 0.22 | 0.25 |
| D           | 9.90 BSC |      |      |
| E           | 6.00 BSC |      |      |
| E1          | 3.90 BSC |      |      |
| e           | 1.27 BSC |      |      |
| h           | 0.25     | ---  | 0.50 |
| L           | 0.40     | 0.83 | 1.25 |
| L1          | 1.05 REF |      |      |
| θ           | 0°       | ---  | 7°   |

| TOLERANCE OF FORM AND POSITION |      |
|--------------------------------|------|
| aaa                            | 0.10 |
| bbb                            | 0.20 |
| ccc                            | 0.10 |
| ddd                            | 0.25 |
| eee                            | 0.10 |



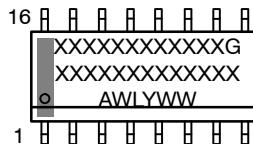
## RECOMMENDED MOUNTING FOOTPRINT

\*FOR ADDITIONAL INFORMATION ON OUR  
PB-FREE STRATEGY AND SOLDERING DETAILS,  
PLEASE DOWNLOAD THE onsemi SOLDERING  
AND MOUNTING TECHNIQUES REFERENCE  
MANUAL, SOLDERRM/D

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**GENERIC  
MARKING DIAGRAM\***



XXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot

Y = Year

WW = Work Week

G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

**STYLE 1:**  
 PIN 1. COLLECTOR  
 2. BASE  
 3. Emitter  
 4. NO CONNECTION  
 5. Emitter  
 6. BASE  
 7. COLLECTOR  
 8. COLLECTOR  
 9. BASE  
 10. Emitter  
 11. NO CONNECTION  
 12. Emitter  
 13. BASE  
 14. COLLECTOR  
 15. Emitter  
 16. COLLECTOR

**STYLE 2:**  
 PIN 1. CATHODE  
 2. ANODE  
 3. NO CONNECTION  
 4. CATHODE  
 5. CATHODE  
 6. NO CONNECTION  
 7. ANODE  
 8. CATHODE  
 9. CATHODE  
 10. ANODE  
 11. NO CONNECTION  
 12. CATHODE  
 13. CATHODE  
 14. NO CONNECTION  
 15. ANODE  
 16. CATHODE

**STYLE 3:**  
 PIN 1. COLLECTOR, DYE #1  
 2. BASE, #1  
 3. Emitter, #1  
 4. COLLECTOR, #1  
 5. COLLECTOR, #2  
 6. BASE, #2  
 7. Emitter, #2  
 8. COLLECTOR, #2  
 9. COLLECTOR, #3  
 10. BASE, #3  
 11. Emitter, #3  
 12. COLLECTOR, #3  
 13. COLLECTOR, #4  
 14. BASE, #4  
 15. Emitter, #4  
 16. COLLECTOR, #4

**STYLE 4:**  
 PIN 1. COLLECTOR, DYE #1  
 2. COLLECTOR, #1  
 3. COLLECTOR, #2  
 4. COLLECTOR, #2  
 5. COLLECTOR, #3  
 6. COLLECTOR, #3  
 7. COLLECTOR, #4  
 8. COLLECTOR, #4  
 9. BASE, #4  
 10. Emitter, #4  
 11. BASE, #3  
 12. Emitter, #3  
 13. BASE, #2  
 14. Emitter, #2  
 15. BASE, #1  
 16. Emitter, #1

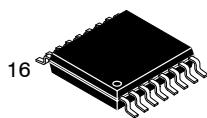
**STYLE 5:**  
 PIN 1. DRAIN, DYE #1  
 2. DRAIN, #1  
 3. DRAIN, #2  
 4. DRAIN, #2  
 5. DRAIN, #3  
 6. DRAIN, #3  
 7. DRAIN, #4  
 8. DRAIN, #4  
 9. GATE, #4  
 10. SOURCE, #4  
 11. GATE, #3  
 12. SOURCE, #3  
 13. GATE, #2  
 14. SOURCE, #2  
 15. GATE, #1  
 16. SOURCE, #1

**STYLE 6:**  
 PIN 1. CATHODE  
 2. CATHODE  
 3. CATHODE  
 4. CATHODE  
 5. CATHODE  
 6. CATHODE  
 7. CATHODE  
 8. CATHODE  
 9. ANODE  
 10. ANODE  
 11. ANODE  
 12. ANODE  
 13. ANODE  
 14. ANODE  
 15. ANODE  
 16. ANODE

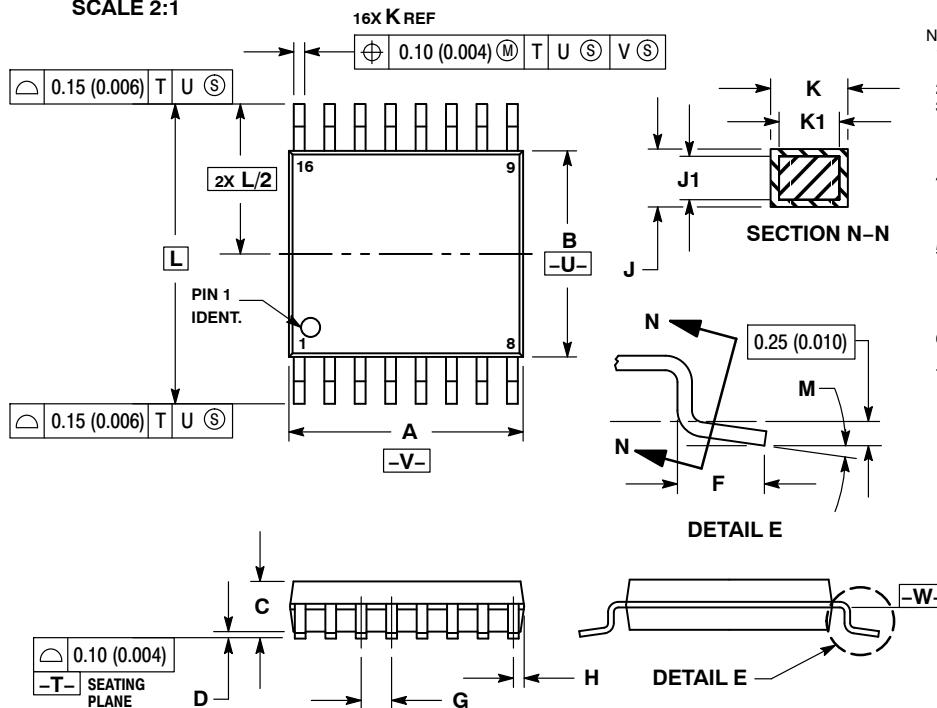
**STYLE 7:**  
 PIN 1. SOURCE N-CH  
 2. COMMON DRAIN (OUTPUT)  
 3. COMMON DRAIN (OUTPUT)  
 4. GATE P-CH  
 5. COMMON DRAIN (OUTPUT)  
 6. COMMON DRAIN (OUTPUT)  
 7. COMMON DRAIN (OUTPUT)  
 8. SOURCE P-CH  
 9. SOURCE P-CH  
 10. COMMON DRAIN (OUTPUT)  
 11. COMMON DRAIN (OUTPUT)  
 12. COMMON DRAIN (OUTPUT)  
 13. GATE N-CH  
 14. COMMON DRAIN (OUTPUT)  
 15. COMMON DRAIN (OUTPUT)  
 16. SOURCE N-CH

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1  
SCALE 2:1TSSOP-16 WB  
CASE 948F  
ISSUE B

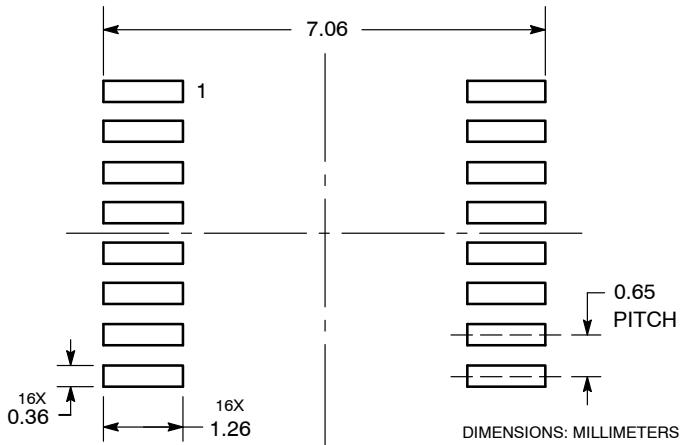
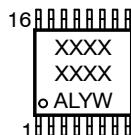
DATE 19 OCT 2006



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES |       |
|-----|-------------|------|--------|-------|
|     | MIN         | MAX  | MIN    | MAX   |
| A   | 4.90        | 5.10 | 0.193  | 0.200 |
| B   | 4.30        | 4.50 | 0.169  | 0.177 |
| C   | ---         | 1.20 | ---    | 0.047 |
| D   | 0.05        | 0.15 | 0.002  | 0.006 |
| F   | 0.50        | 0.75 | 0.020  | 0.030 |
| G   | 0.65        | BSC  | 0.026  | BSC   |
| H   | 0.18        | 0.28 | 0.007  | 0.011 |
| J   | 0.09        | 0.20 | 0.004  | 0.008 |
| J1  | 0.09        | 0.16 | 0.004  | 0.006 |
| K   | 0.19        | 0.30 | 0.007  | 0.012 |
| K1  | 0.19        | 0.25 | 0.007  | 0.010 |
| L   | 6.40        | BSC  | 0.252  | BSC   |
| M   | 0°          | 8°   | 0°     | 8°    |

RECOMMENDED  
SOLDERING FOOTPRINT\*GENERIC  
MARKING DIAGRAM\*

XXXX = Specific Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 W = Work Week  
 G or □ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "□", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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